

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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NEC

HIGH CTR, AC INPUT RESPONSE TYPE 4 PIN ULTRA SMALL PACKAGE FLAT LEAD OPTOCOUPLER

PS2915-1

FEATURES

- ULTRA SMALL FLAT-LEAD PACKAGE: 4.6 (L) x 2.5 (W) x 2.1 (H) mm
- HIGH CURRENT TRANSFER RATIO: CTR = 200% TYP @ IF = ± 1 mA, VCE = 5 V
- HIGH ISOLATION VOLTAGE BV: 2500 Vr.m.s.
- TAPE AND REEL AVAILABLE: PS2915-F3, F4: 3500 pcs/reel

DESCRIPTION

The PS2915-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor in one package for high density mounting applications. An ultra small flat lead package has been provided which realizes a reduction in mounting area of about 30% compared with the PS28XX series.

APPLICATIONS

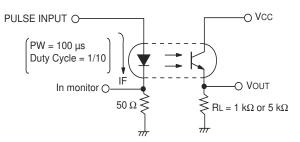
- DC/DC CONVERTER
- · MODEM/PC CARD

ELECTRICAL CHARACTERISTICS (TA = 25°C)

		PART NUMBER	PS2915-1			
	SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
de	VF	Forward Voltage, $IF = \pm 1 \text{ mA}$	V	0.9	1.1	1.3
Diode	Ст	Terminal Capacitance, V = 0, f = 1.0 MHz	pF		30	
Transistor	ICEO	Collector to Emitter Dark Current, IF = 0 mA, VcE = 40 V	nA			100
	CTR	Current Transfer Ratio (Ic/IF) ¹ , IF = ± 1 mA, VCE = 5 V	%	100	200	400
Coupled	VCE(sat)	Collector Saturation Voltage, IF = ±1 mA, Ic = 0.2 mA	V		0.13	0.3
	Rı-o	Isolation Resistance, Vi-o = 1.0 kVpc	Ω	1011		
	Cı-o	Isolation Capacitance, V = 0 V, f = 1.0 MHz	pF		0.4	
	tr	Rise Time ² , Vcc = 5 V, Ic = 2 mA, RL = 1 k Ω	μS		5	
	tf	Fall Time ² , Vcc = 5 V, Ic = 2 mA, RL = 1 k Ω	μS		10	
	ton	On Time, Vcc = 5 V, IF = ± 1 mA, RL = 5 k Ω	μS		40	
	ts	Storage Time ² , Vcc = 5 V, IF = ± 1 mA, RL = 5 k Ω	μS		10	
	toff	Off Time ² , Vcc = 5 V, IF = ± 1 mA, RL = 5 k Ω	μS		120	

Notes:

- 1. CTR RANK:
 - N: 100 to 400 (%)
- 2. Test Circuit for Switching Time





ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

PARAMETERS	UNITS	RATINGS			
Diode					
Forward Current	mA	±50			
ΔIF/°C Forward Current Derating		0.5			
Peak Forward Current ²	Α	±0.5			
PD Power Dissipation		60			
Transistor					
Collector to Emitter Voltage	V	40			
Emitter to Collector Voltage	V	5			
Collector Current	mA	40			
Power Dissipation Derating	mW/°C	1.2			
Power Dissipation	mW	120			
Coupled					
Isolation Voltage ³	Vr.m.s.	2500			
Total Power Dissipation	mW	160			
Operating Ambient Temp.	°C	-55 to +100			
Storage Temperature	°C	-55 to +150			
	Forward Current Forward Current Derating Peak Forward Current² Power Dissipation Collector to Emitter Voltage Emitter to Collector Voltage Collector Current Power Dissipation Derating Power Dissipation Isolation Voltage³ Total Power Dissipation Operating Ambient Temp.	Forward Current mA Forward Current Derating mW/°C Peak Forward Current² A Power Dissipation mW Collector to Emitter Voltage V Emitter to Collector Voltage V Collector Current mA Power Dissipation Derating mW/°C Power Dissipation Derating mW Isolation Voltage³ Vr.m.s. Total Power Dissipation mW Operating Ambient Temp. °C			

Notes:

- Operation in excess of any one of these parameters may result in permanent damage.
- 2. $\overrightarrow{PW} = 100 \ \mu s$, Duty Cycle = 1%.
- 3. AC voltage for 1 minute at Ta = 25 °C, RH = 60 % between input and output.

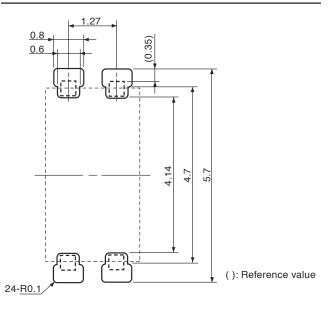
CAUTIONS REGARDING NOISE:

Be aware that when voltage is applied suddenly between the optocoupler's input and outout or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

ORDERING INFORMATION

PART NUMBER	PACKING STYLE
PS2915-1-F3	Embossed Tape 3500 pcs/reel
PS2915-1-F4	

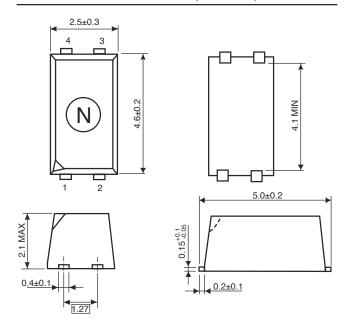
RECOMMENDED MOUNT PAD DIMENSIONS (Units in mm)



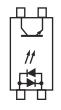
OPTOCOUPLER CONSTRUCTION

PARAMETER	UNITS (MIN)	
Air Distance	4 mm	
Creepage Distance	4 mm	
Isolation Distance	0.4 mm	

OUTLINE DIMENSIONS (Units in mm)

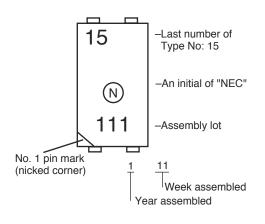


TOP VIEW

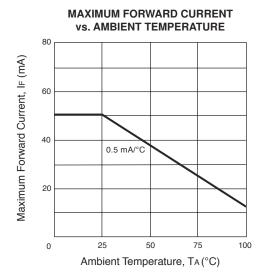


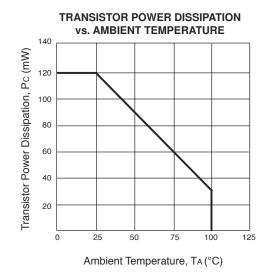
- 1. Anode, Cathode
- 2. Cathode, Anode
- 3. Emitter
- 4. Collector

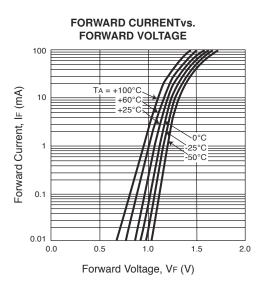
MARKING

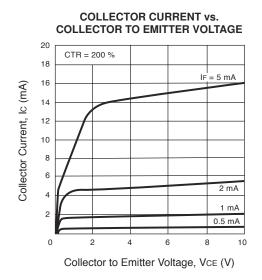


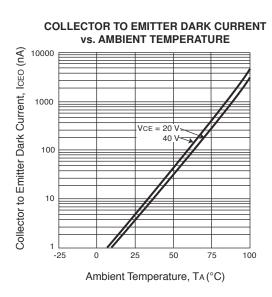
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)

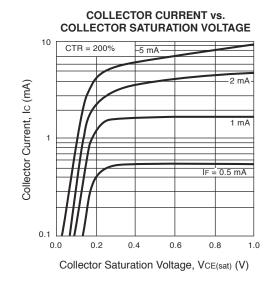




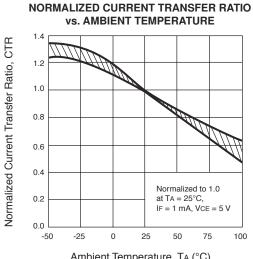


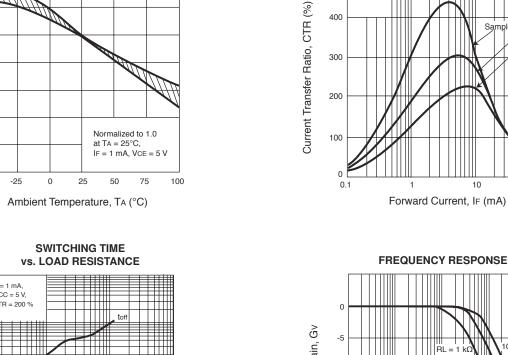


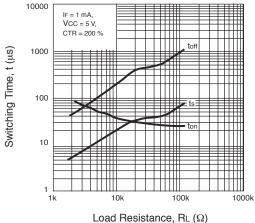


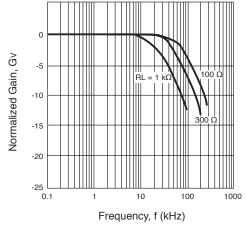


TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)









CURRENT TRANSFER RATIO

vs. FORWARD CURRENT

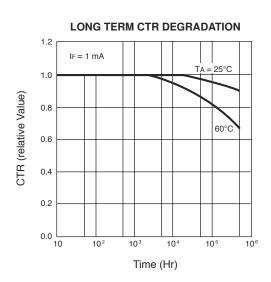
100

500

400

300

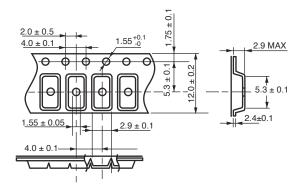
VCE = 5 V n = 3



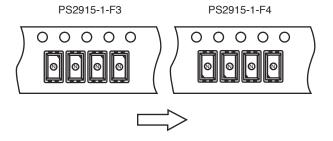
Remark: The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (Units in mm)

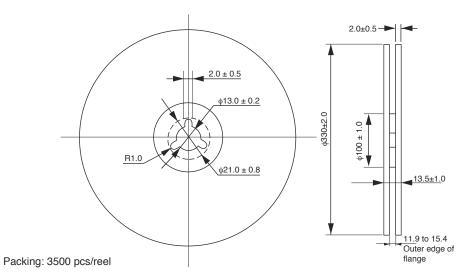
Tape Outline and Dimensions



Tape Direction



Reel Outline and Dimensions



RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

Peak reflow temperature
 260 °C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220 °C
 60 seconds or less

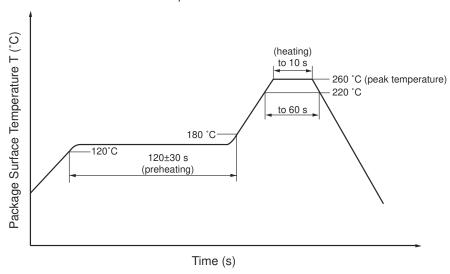
Time to preheat temperature from 120 to 180°C 120±30 s

Number of reflows
 Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is

recommended).

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

Temperature 260 °C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times
 One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt % is recommended).

(3) Cautions

• Fluxes Avoid removing the residual flux with chlorine-based cleaning solvent after a reflow process.

USAGE CAUTIONS

- 1. Protect against static electricity when handling
- 2. Avoid storage at a high temperature and high humidity.

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.